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# S32K1XX

## S32K1xx Data Sheet

### Caution

- S32K148, S32K142, S32K146, and S32K116 specific information is preliminary until these devices are qualified.

### Key Features

- Operating characteristics
  - Voltage range: 2.7 V to 5.5 V
  - Ambient temperature range: -40 °C to 105 °C for HSRUN, -40 °C to 125 °C for RUN
- ARM™ Cortex-M4F/M0+ core, 32-bit CPU
  - Supports up to 112 MHz frequency (HSRUN) with 1.25 Dhrystone MIPS per MHz
  - ARM Core based on the ARMv7 Architecture and Thumb®-2 ISA
  - Integrated Digital Signal Processor (DSP)
  - Configurable Nested Vectored Interrupt Controller (NVIC)
  - Single Precision Floating Point Unit (FPU)
- Clock interfaces
  - 4 - 40 MHz fast external oscillator (SOSC)
  - 48 MHz Fast Internal RC oscillator (FIRC)
  - 8 MHz Slow Internal RC oscillator (SIRC)
  - 128 kHz Low Power Oscillator (LPO)
  - Up to 112 MHz (HSRUN) System Phased Lock Loop (SPLL)
  - Up to 50 MHz DC external square wave input clock
  - Real Time Counter (RTC)
- Power management
  - Low-power ARM Cortex-M4F/M0+ core with excellent energy efficiency
  - Power Management Controller (PMC) with multiple power modes: HSRUN, Run, Stop, VLPR, and VLPS
  - Supports peripheral specific clock gating. Only specific peripherals remain working in low power modes.
- Memory and memory interfaces
  - Up to 2 MB program flash memory with ECC
  - 64 KB FlexNVM for data flash memory with ECC and EEPROM emulation
  - Up to 256 KB SRAM with ECC
  - Up to 4 KB of FlexRAM for use as SRAM or EEPROM emulation
  - Up to 4 KB Code cache to minimize performance impact of memory access latencies
  - QuadSPI with HyperBus™ support
- Mixed-signal analog
  - Up to two 12-bit Analog-to-Digital Converter (ADC) with up to 32 channel analog inputs per module
  - One Analog Comparator (CMP) with internal 8-bit Digital to Analog Converter (DAC)
- Debug functionality
  - Serial Wire JTAG Debug Port (SWJ-DP) combines
  - Debug Watchpoint and Trace (DWT)
  - Instrumentation Trace Macrocell (ITM)
  - Test Port Interface Unit (TPIU)
  - Flash Patch and Breakpoint (FPB) Unit
- Human-machine interface (HMI)
  - Up to 156 GPIO pins with interrupt functionality
  - Non-Maskable Interrupt (NMI)
- Communications interfaces
  - Up to three Low Power Universal Asynchronous Receiver/Transmitter (LPUART) modules with DMA support and low power availability
  - Up to three Low Power Serial Peripheral Interface (LPSPI) modules with DMA support and low power availability
  - Up to two Low Power Inter-Integrated Circuit (LPI2C) modules with DMA support and low power availability
  - Up to three FlexCAN modules (with optional CAN-FD support)
  - FlexIO module for flexible and high performance serial interfaces

This document contains information on a product under development. NXP reserves the right to change or discontinue this product without notice.



- Reliability, safety and security
  - HW Security Engine (CSEc)
  - Internal watchdog (WDOG)
  - External Watchdog monitor (EWM) module
  - Error-Correcting Code (ECC) on flash and SRAM memories
  - Cyclic Redundancy Check (CRC) module
  - 128-bit Unique Identification (ID) number
  - System Memory Protection Unit (System MPU)
- Timing and control
  - Up eight independent 16-bit FlexTimers (FTM) module, offering up to 64 standard channels (IC/OC/PWM)
  - One 16-bit Low Power Timer (LPTMR) with flexible wake up control
  - Two Programmable Delay Blocks (PDB) with flexible trigger system
  - One 32-bit Low Power Interrupt Timer (LPIT) with 4 channels
  - 32-bit Real Time Counter (RTC)
- I/O and package
  - 32-pin QFN, 48-pin LQFP, 64-pin LQFP, 100-pin LQFP, MAPBGA-100, 144-pin LQFP, 176-pin LQFP package options
- 16 channel DMA with up to 63 request sources using DMAMUX



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# 1 Block diagram

Following figures show superset high level architecture block diagrams of S32K14x series and S32K11x series respectively. Other devices within the family have a subset of the features. See [Feature comparison](#) for chip specific values.

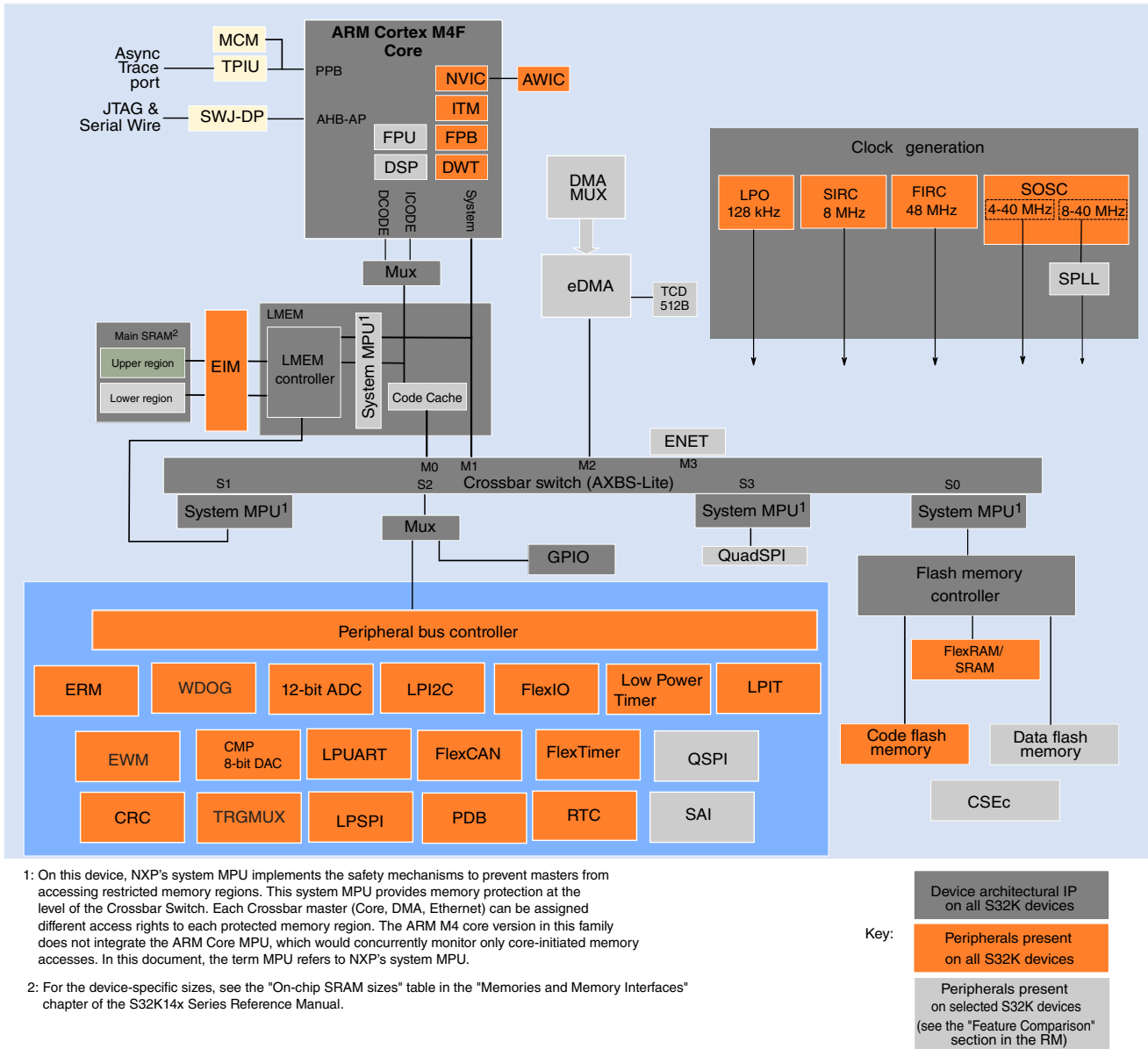
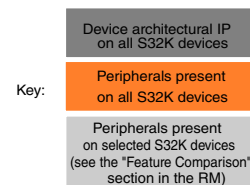


Figure 1. High-level architecture diagram for the S32K14x family



## 2 Feature comparison

The following figure summarizes the memory and package options for the S32K product series and demonstrates where this device fits within the overall series. All devices which share a common package are pin-to-pin compatible.

## Feature comparison

		S32K11x		S32K14x			
Parameter		K116	K118	K142	K144	K146	K148
System	Core	ARM® Cortex™-M0+		ARM® Cortex™-M4F			
	Frequency	48 MHz		up to 112 MHz (HSRUN)			
	IEEE-754 FPU	○		●			
	HW security module (CSEc) <sup>1</sup>	●		●			
	CRC module	1x		1x			
	ISO 26262	capable up to ASIL-B		capable up to ASIL-B			
	Peripheral speed	up to 48 MHz		up to 112 MHz (HSRUN)			
	Crossbar	●		●			
	DMA	●		●			
	EWM	○		●			
	Memory protection unit	●		●			
	FIRC CMU	●		○			
	Watchdog	1x		1x			
	Low power modes	●		●			
	HSRUN mode	○		●			
	Number of I/Os	up to 43	up to 58	up to 89	up to 128	up to 128	up to 156
	Single supply voltage	2.7 - 5.5 V		2.7 - 5.5 V			
	Operating temperature (T <sub>a</sub> ) Temperature ambient	-40 to +85°C / +105°C / +125°C		-40 to +85°C / +105°C / +125°C			
Memory	Flash	128 KB	256 KB	256 KB	512 KB	1 MB	2 MB <sup>2</sup>
	Error correction code (ECC)	●		●			
	System RAM (including FlexRAM and MTB)	17 KB	25 KB	32 KB	64 KB	128 KB	256 KB
	FlexRAM (also available as system RAM)	2 KB		4 KB			
	Cache	○		4 KB			
	EEPROM emulated by FlexRAM <sup>1</sup>	2 KB (up to 32 KB D-Flash)		4 KB (up to 64 KB D-Flash)			4 KB (up to 512 KB D-Flash as a part of 2 MB Flash) <sup>3</sup>
	External memory interface	○		○			QuadSPI incl. HyperBus™
Timer	Low power interrupt timer	1x		1x			
	FlexTimer (16-bit counter) 8 channels	2x (16)		4x (32)		6x (48)	8x (64)
	Low power timer (LPTMR)	1x		1x			
	Real time counter (RTC)	1x		1x			
	Programmable delay block (PDB)	1x		2x			
Analog	Trigger mux (TRGMUX)	1x (43)	1x (45)	1x (64)		1x (73)	1x (81)
	12-bit SAR ADC (1 MSPS each)	1x (14)	1x (16)	2x (16)		2x (24)	2x (32)
	Comparator with 8-bit DAC	1x		1x			
Communication	100 Mbit IEEE-1588 ethernet MAC	○		○			1x
	Serial audio interface (AC97, TDM, I2S)	○		○			2x
	Low power UART/LIN (Supports LIN protocol versions 1.3, 2.0, 2.1, and SAE J2602)	2x		2x	3x		
	Low power SPI	1x	2x	2x	3x		
	Low power I2C	1x		1x			2x
	FlexCAN (CAN-FD ISO/CD 11898-1)	1x (1x with FD)		2x (1x with FD)	3x (1x with FD)	3x (2x with FD)	3x (3x with FD)
	FlexIO (8 pins configurable as UART, SPI, I2C, I2S)	1x		1x			
IDEs	Debug & trace	SWD, MTB (1 KB), JTAG <sup>4</sup>		SWD, JTAG (ITM, SWV, SWO)			SWD, JTAG (ITM, SWV, SWO), ETM
	Ecosystem (IDE, compiler, debugger)	NXP S32 Design Studio (GCC) + SDK, IAR, GHS, COSMIC, Lauterbach, iSystems		NXP S32 Design Studio (GCC) + SDK, IAR, GHS, COSMIC, Lauterbach, iSystems			
Other	Packages	QFN-32 LQFP-48	LQFP-48 LQFP-64	LQFP-64 LQFP-100	LQFP-64 LQFP-100 MAPBGA-100	LQFP-64 MAPBGA-100 LQFP-100 LQFP-144	MAPBGA-100 LQFP-144 LQFP-176

### LEGEND:

○ Not implemented

● Available on the device

<sup>1</sup> No FTFC commands, including CSE commands (CSEc parts) are available when chip is in VLPR or HSRUN mode.

<sup>2</sup> Available when EEPROM, CSEc and Data Flash are not used. Else only up to 1,984 KB is available for Program Flash.

<sup>3</sup> Up to 64 KB of flash is used as EEPROM backup and the remaining 448 KB of the last 512 KB block can be used as Data flash or Program flash.

See chapter FTFC for details.

<sup>4</sup> Only for BSR

**Figure 3. S32K1xx product series comparison**

## 3 Ordering parts

### 3.1 Determining valid orderable parts

To determine the orderable part numbers for this device, go to [www.nxp.com](http://www.nxp.com) and perform a part number search. Additionally see the attachment *S32K\_Part\_Numbers.xlsx*.

#### NOTE

Not all part number combinations exist



## 3.2 Ordering information

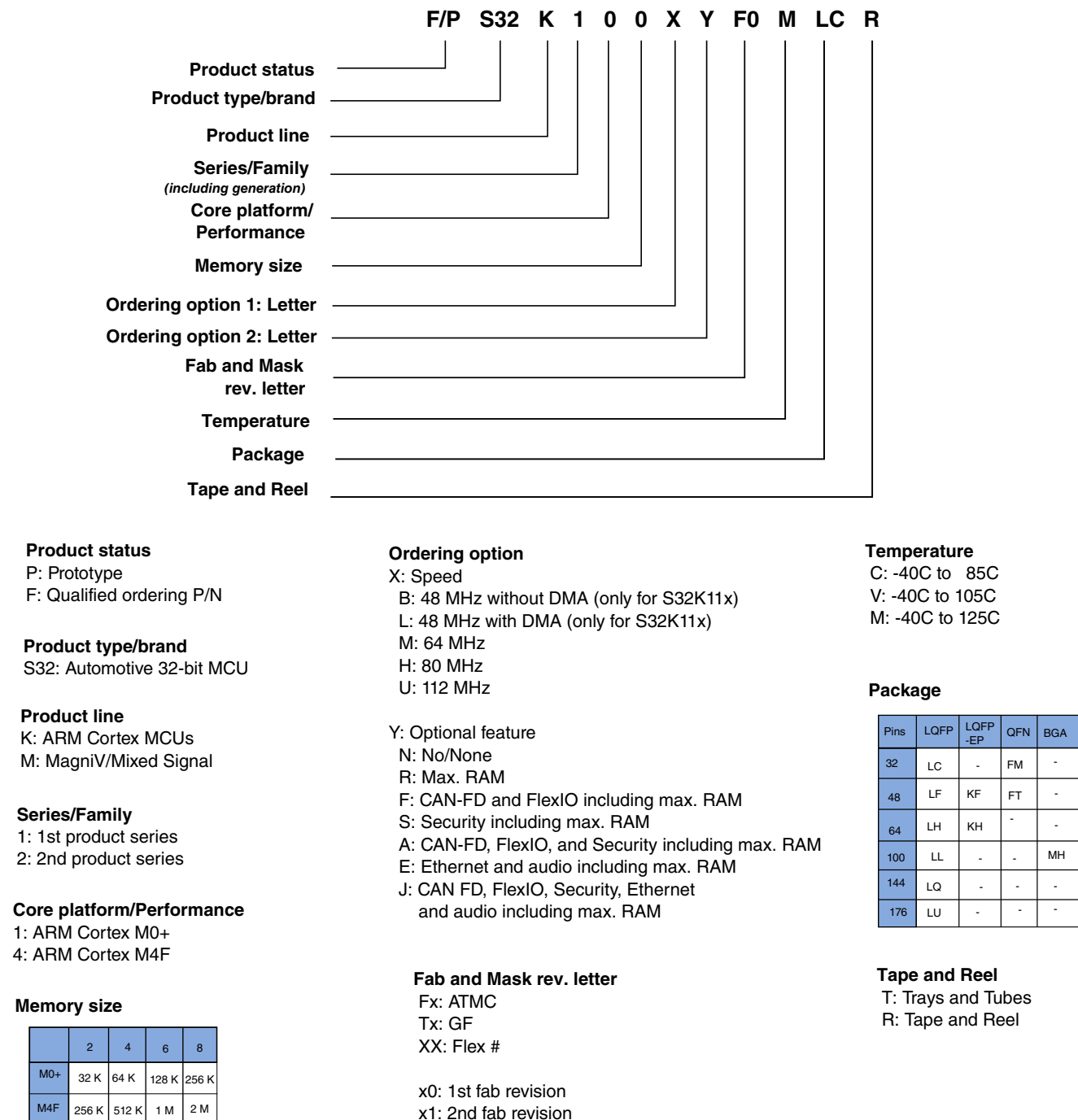


Figure 4. Ordering information

## 4 General

### 4.1 Absolute maximum ratings

#### NOTE

Functional operating conditions appear in the DC electrical characteristics. Absolute maximum ratings are stress ratings only, and functional operation at the maximum values is not guaranteed. See footnotes in the following table for specific conditions.

Stress beyond the listed maximum values may affect device reliability or cause permanent damage to the device.

All the limits defined in the datasheet specification must be honored together and any violation to any one or more will not guarantee desired operation.

**Table 1. Absolute maximum ratings**

Symbol	Parameter	Conditions <sup>1</sup>	Min	Max	Unit
$V_{DD}$ <sup>2</sup>	2.7 V - 5.5 V input supply voltage	—	-0.3	5.8 <sup>3</sup>	V
$V_{REFH}$	3.3 V / 5.0 V ADC high reference voltage	—	-0.3	5.8 <sup>3</sup>	V
$I_{INJPAD\_DC\_ABS}$ <sup>4</sup>	Continuous DC input current (positive / negative) that can be injected into an I/O pin	—	-3	+3	mA
$V_{IN\_DC}$	Continuous DC Voltage on any I/O pin with respect to $V_{SS}$	—	-0.8	5.8 <sup>5</sup>	V
$I_{INJSUM\_DC\_ABS}$	Sum of absolute value of injected currents on all the pins (Continuous DC limit)	—	—	30	mA
$T_{ramp}$ <sup>6</sup>	Supply ramp rate	—	0.5 V/min	500 V/ms	—
$T_A$ <sup>7</sup>	Ambient temperature	—	-40	125	°C
$T_{STG}$	Storage temperature	—	-55	165	°C
$V_{IN\_TRANSIENT}$	Transient overshoot voltage allowed on I/O pin beyond $V_{IN\_DC}$ limit	—	—	6.8 <sup>8</sup>	V

1. All voltages are referred to  $V_{SS}$  unless otherwise specified.
2. As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
3. 60 s lifetime – No restrictions i.e. The part can switch.  
10 hours lifetime – Device in reset i.e. The part cannot switch.
4. When input pad voltage levels are close to  $V_{DD}$  or  $V_{SS}$ , practically no current injection is possible.
5. While respecting the maximum current injection limit
6. Limit applies to both maximum absolute maximum ramp rate and typical operating conditions.
7.  $T_J$  (Junction temperature)=135 °C. Assumes  $T_A$ =125 °C for RUN mode

## General

$T_J$  (Junction temperature)=125 °C. Assumes  $T_A$ =105 °C for HSRUN mode

- Assumes maximum  $\theta_{JA}$  for 2s2p board. See [Thermal characteristics](#)

8. 60 seconds lifetime; device in reset (no outputs enabled/toggling)

## 4.2 Voltage and current operating requirements

### NOTE

Full functionality/specifications cannot be guaranteed when voltage drops below 2.7 V.

**Table 2. Voltage and current operating requirements 1**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DD}$ <sup>2</sup>	Supply voltage	2.7 <sup>3</sup>	5.5	V	4
$V_{DD\_OFF}$	Voltage allowed to be developed on $V_{DD}$ pin when it is not powered from any external power supply source.	0	0.1	V	
$V_{DDA}$	Analog supply voltage	2.7	5.5	V	4
$V_{DD} - V_{DDA}$	$V_{DD}$ -to- $V_{DDA}$ differential voltage	-0.1	0.1	V	
$V_{REFH}$	ADC reference voltage high	2.7	$V_{DDA} + 0.1$	V	5
$V_{REFL}$	ADC reference voltage low	-0.1	0.1	V	
$V_{ODPU}$	Open drain pullup voltage level	$V_{DD}$	$V_{DD}$	V	6
$I_{INJPAD\_DC\_OP}$ <sup>7</sup>	Continuous DC input current (positive / negative) that can be injected into an I/O pin	-3	+3	mA	
$I_{INJSUM\_DC\_OP}$	Continuous total DC input current that can be injected across all I/O pins such that there's no degradation in accuracy of analog modules: ADC and ACMP (See section <a href="#">Analog Modules</a> )	—	30	mA	

- Typical conditions assumes  $V_{DD} = V_{DDA} = V_{REFH} = 5$  V, temperature = 25 °C and typical silicon process unless otherwise stated.
- As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
- S32K148 will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged S32K148 is guaranteed to operate from 2.97 V. All other S32K family devices operate from 2.7 V in all modes.
- $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note [AN5032](#) for reference supply design for SAR ADC.
- $V_{REFH}$  should always be equal to or less than  $V_{DDA} + 0.1$  V and  $V_{DD} + 0.1$  V
- Open drain outputs must be pulled to  $V_{DD}$ .
- When input pad voltage levels are close to  $V_{DD}$  or  $V_{SS}$ , practically no current injection is possible.

### 4.3 Thermal operating characteristics

**Table 3. Thermal operating characteristics for 64 LQFP, 100 LQFP, and 100 MAP-BGA packages.**

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
$T_A$ C-Grade Part	Ambient temperature under bias	-40	—	85 <sup>1</sup>	°C
$T_J$ C-Grade Part	Junction temperature under bias	-40	—	105 <sup>1</sup>	°C
$T_A$ V-Grade Part	Ambient temperature under bias	-40	—	105 <sup>1</sup>	°C
$T_J$ V-Grade Part	Junction temperature under bias	-40	—	125 <sup>1</sup>	°C
$T_A$ M-Grade Part	Ambient temperature under bias	-40	—	125 <sup>2</sup>	°C
$T_J$ M-Grade Part	Junction temperature under bias	-40	—	135 <sup>2</sup>	°C

1. Values mentioned are measured at  $\leq 112$  MHz in HSRUN mode.
2. Values mentioned are measured at  $\leq 80$  MHz in RUN mode.

## 4.4 Power and ground pins

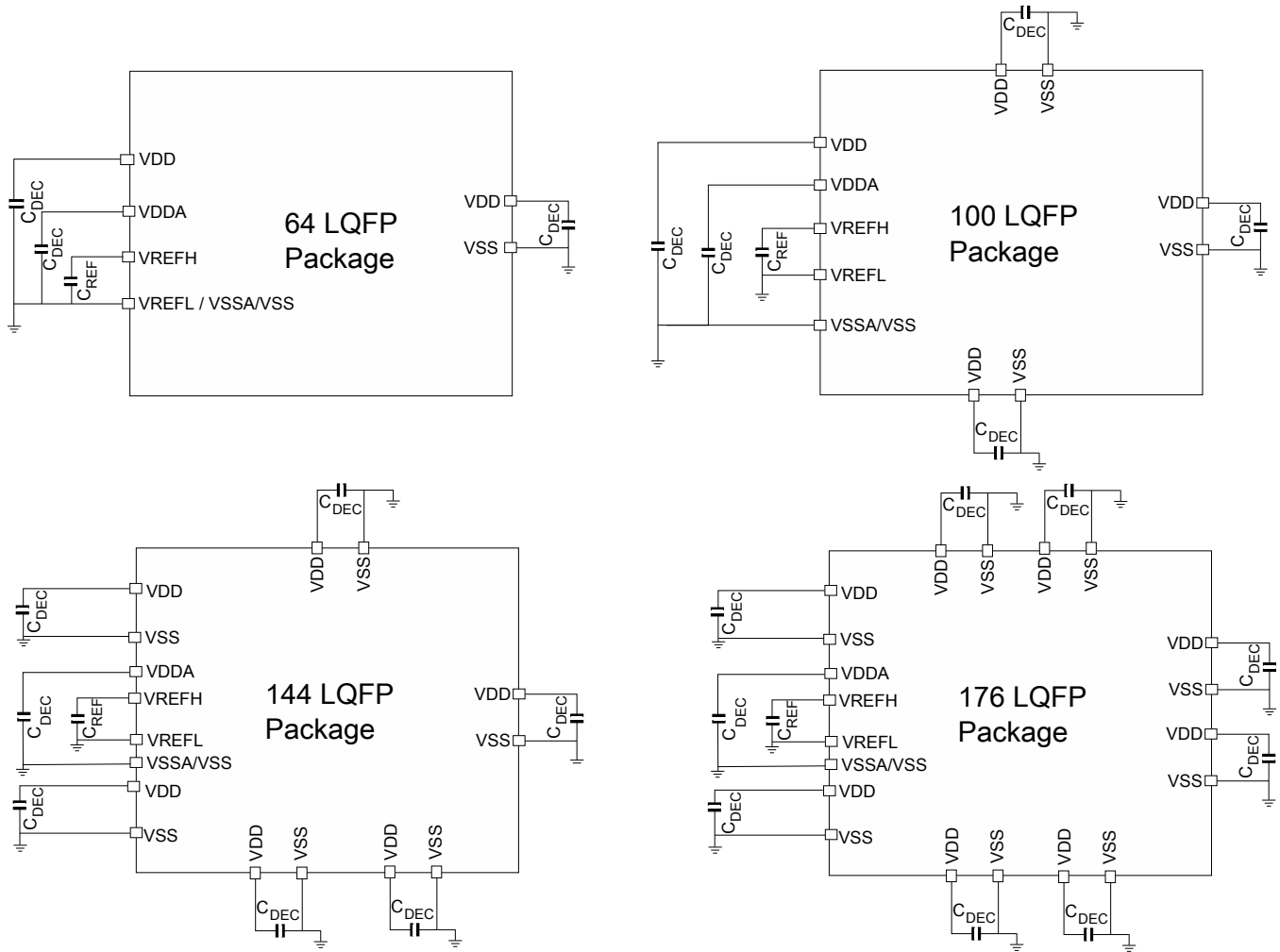


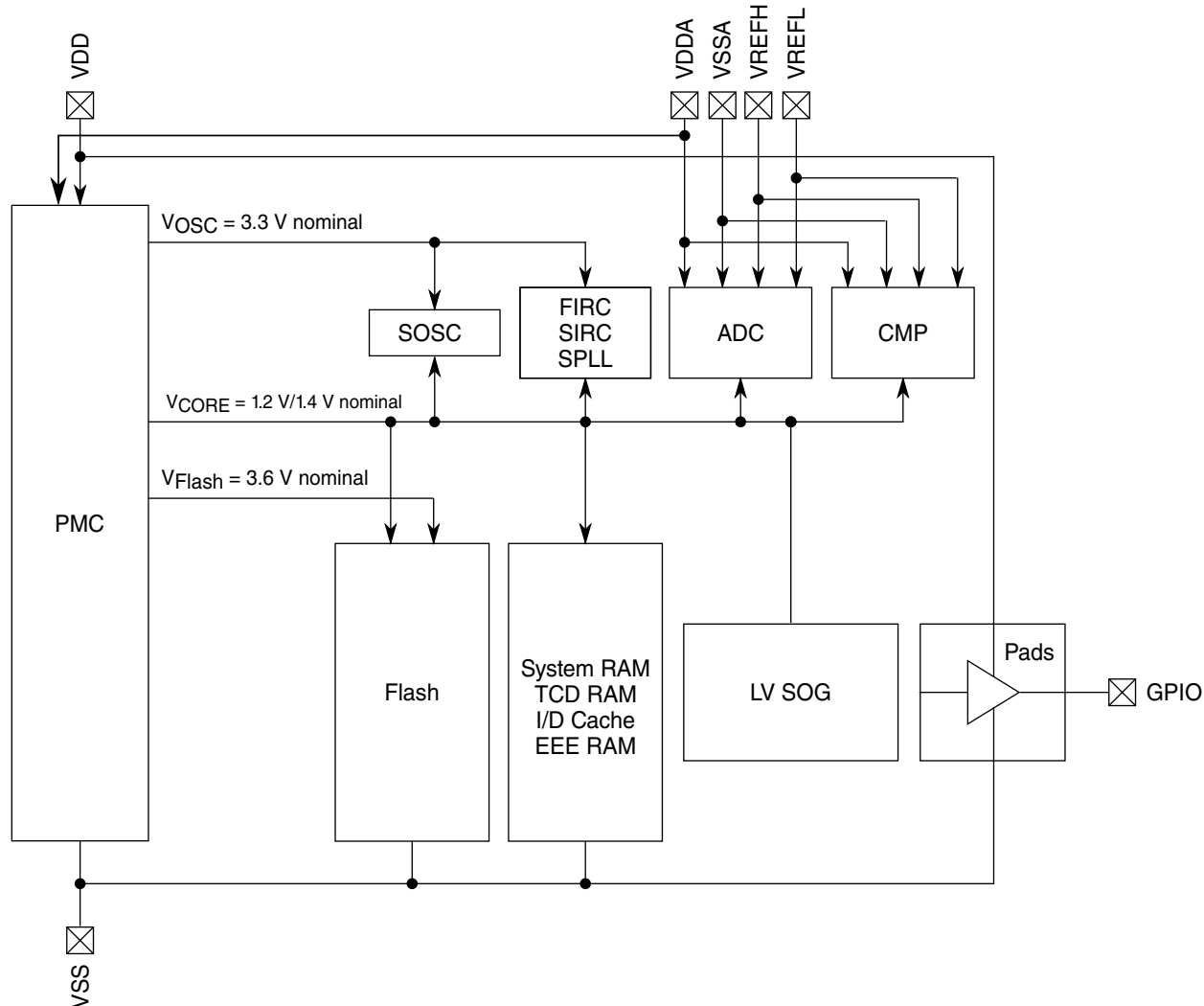
Figure 5. Pinout decoupling

Table 4. Supplies decoupling capacitors 1, 2

Symbol	Description	Min. <sup>3</sup>	Typ.	Max.	Unit
$C_{REF}^{4, 5}$	ADC reference high decoupling capacitance	70	100	—	nF
$C_{DEC}^{5, 6, 7}$	Recommended decoupling capacitance	70	100	—	nF

- $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note AN5032 for reference supply design for SAR ADC. All  $V_{SS}$  pins should be connected to common ground at the PCB level.
- All decoupling capacitors must be low ESR ceramic capacitors (for example X7R type).
- Minimum recommendation is after considering component aging and tolerance.
- For improved performance, it is recommended to use 10  $\mu$ F, 0.1  $\mu$ F and 1 nF capacitors in parallel.
- All decoupling capacitors should be placed as close as possible to the corresponding supply and ground pins.
- Contact your local Field Applications Engineer for details on best analog routing practices.
- The filtering used for decoupling the device supplies must comply with the following best practices rules:
  - The protection/decoupling capacitors must be on the path of the trace connected to that component.

- No trace exceeding 1 mm from the protection to the trace or to the ground.
- The protection/decoupling capacitors must be as close as possible to the input pin of the device (maximum 2 mm).
- The ground of the protection is connected as short as possible to the ground plane under the integrated circuit.



\*Note: VSSA and VSS are shorted at package level

**Figure 6. Power diagram**

## 4.5 LVR, LVD and POR operating requirements

**Table 5.  $V_{DD}$  supply LVR, LVD and POR operating requirements**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$V_{POR}$	Rising and falling $V_{DD}$ POR detect voltage	1.1	1.6	2.0	V	
$V_{LVR}$	LVR falling threshold (RUN, HSRUN, and STOP modes)	2.50	2.58	2.7	V	
$V_{LVR\_HYST}$	LVR hysteresis	—	45	—	mV	1
$V_{LVR\_LP}$	LVR falling threshold (VLPS/VLPR modes)	1.97	2.22	2.44	V	

Table continues on the next page...



**Table 5.  $V_{DD}$  supply LVR, LVD and POR operating requirements (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$V_{LVD}$	Falling low-voltage detect threshold	2.8	2.875	3	V	
$V_{LVD\_HYST}$	LVD hysteresis	—	50	—	mV	1
$V_{LVW}$	Falling low-voltage warning threshold	4.19	4.305	4.5	V	
$V_{LVW\_HYST}$	LVW hysteresis	—	75	—	mV	1
$V_{BG}$	Bandgap voltage reference	0.97	1.00	1.03	V	

1. Rising threshold is the sum of falling threshold and hysteresis voltage.

## 4.6 Power mode transition operating behaviors

All specifications in the following table assume this clock configuration:

- RUN Mode:
  - Clock source: FIRC
  - SYS\_CLK/CORE\_CLK = 48 MHz
  - BUS\_CLK = 48 MHz
  - FLASH\_CLK = 24 MHz
- HSRUN Mode:
  - Clock source: SPLL
  - SYS\_CLK/CORE\_CLK = 112 MHz
  - BUS\_CLK = 56 MHz
  - FLASH\_CLK = 28 MHz
- VLPR Mode:
  - Clock source: SIRC
  - SYS\_CLK/CORE\_CLK = 4 MHz
  - BUS\_CLK = 4 MHz
  - FLASH\_CLK = 1 MHz
- STOP1/STOP2 Mode:
  - Clock source: FIRC
  - SYS\_CLK/CORE\_CLK = 48 MHz
  - BUS\_CLK = 48 MHz
  - FLASH\_CLK = 24 MHz
- VLPS Mode: All clock sources disabled.

**Table 6. Power mode transition operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit
$t_{POR}$	After a POR event, amount of time from the point $V_{DD}$ reaches 2.7 V to execution of the first instruction across the operating temperature range of the chip.	—	325	—	$\mu s$

Table continues on the next page...

**Table 6. Power mode transition operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit
	VLPS → RUN	8	—	17	μs
	STOP1 → RUN	0.07	0.075	0.08	μs
	STOP2 → RUN	0.07	0.075	0.08	μs
	VLPR → RUN	19	—	26	μs
	VLPR → VLPS	5.75	6.25	6.5	μs
	VLPS → VLPR	26.5	27.25	27.75	μs
	RUN → Compute operation	0.35	0.38	0.4	μs
	HSRUN → Compute operation	0.3	0.31	0.35	μs
	RUN → STOP1	0.35	0.38	0.4	μs
	RUN → STOP2	0.2	0.23	0.25	μs
	RUN → VLPS	0.35	0.38	0.4	μs
	RUN → VLPR	4.4	4.7	5	μs
	VLPS → Asynchronous DMA Wakeup	105	110	125	μs
	STOP1 → Asynchronous DMA Wakeup	1	1.1	1.3	μs
	STOP2 → Asynchronous DMA Wakeup	1	1.1	1.3	μs
	Pin reset → Code execution	—	214	—	μs

**NOTE**

HSRUN should only be used when frequencies in excess of 80 MHz are required. When using 80 MHz and below, RUN mode is the recommended operating mode.

**4.7 Power consumption**

The following table shows the power consumption targets for the device in various mode of operations.

Table 7. Power consumption (Typicals unless stated otherwise) 1

	Ambient Temperature (°C)		VLPS (µA) <sup>2, 3</sup>		VLPR (mA)		STOP1 (mA)	STOP2 (mA)	RUN@48 MHz (mA)		RUN@64 MHz (mA)		RUN@80 MHz (mA)		HSRUN@112 MHz (mA) <sup>4</sup>		Idd/MHz (µA/MHz) <sup>5</sup>
			Peripherals disabled <sup>6</sup>	Peripherals enabled	Peripherals disabled	Peripherals enabled			Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	
S32K116	25	Typ	26	38	1.9	2.5	7	12	TBD	TBD	NA						TBD
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA						TBD
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD							TBD
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	40							TBD
S32K118	25	Typ	26	38	1.9	2.5	7	12	TBD	TBD	NA						TBD
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA						TBD
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD							TBD
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	42							TBD
S32K142	25	Typ	29	42	1.9	2.5	10	15	TBD	TBD	NA		TBD	TBD	TBD	TBD	TBD
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD			48	57	65	75	TBD
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD			TBD	TBD	85	90	TBD
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD			60	65	NA		TBD
S32K144	25	Typ	29.8	39.1	1.48	1.50	7	7.7	19.7	26.9	25.1	33.3	30.2	39.6	43.3	55.6	378

Table continues on the next page...

Table 7. Power consumption (Typicals unless stated otherwise) 1 (continued)

	Ambient Temperature (°C)		VLPS (µA) <sup>2, 3</sup>		VLPR (mA)		STOP1 (mA)	STOP2 (mA)	RUN@48 MHz (mA)		RUN@64 MHz (mA)		RUN@80 MHz (mA)		HSRUN@112 MHz (mA) <sup>4</sup>		Idd/MHz (µA/MHz) <sup>5</sup>
	85	Typ	150	159	1.72	1.85	7.2	8.1	20.4	27.1	26.1	33.5	30.5	40	43.9	56.1	381
		Max	359	384	2.60	2.65	8.3	9.2	21.9	28.5	27.8	34.4	32.9	41.5	45.5	57.5	411
	105	Typ	256	273	1.80	2.10	7.8	8.5	20.6	27.4	26.6	33.8	31.2	40.5	44.8	57.1	390
		Max	850	900	2.65	2.70	10.3	10.6	22.7	30	28.3	36.5	33.4	43.3	47.9	61.3	418
	125	Max	1960	1998	3.18	3.25	12.2	13	25.3	32.7	35	39.8	37.1	46.5	NA	NA	464
S32K146	25	Typ	40	55	5	6	15	20	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	95	110	TBD
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	70	80	NA	NA	TBD
S32K148 <sup>7, 8</sup>	25	Typ	40	60	5	6	15	20	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	120	125	TBD
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	100	110	NA	NA	TBD

1. Typical current numbers are indicative for typical silicon process and may vary based on the silicon distribution and user configuration.
2. This is an average based on the use case described in the Comparator section, whereby the analog sampling is taking place periodically, with a mechanism to only enable the DAC as required. The numbers quoted assumes that only a single ANLCMP is active and the others are disabled
3. Current numbers are for reduced configuration and may vary based on user configuration and silicon process variation.
4. HSRUN mode must not be used at 125°C. Max ambient temperature for HSRUN mode is 105°C.
5. Values mentioned are measured at 25 °C at RUN@80 MHz with peripherals disabled.
6. With PMC\_REGSC[CLKBIASDIS] set to 1. See Reference Manual for details.
7. Above S32K148 data is preliminary targets only
8. The S32K148 data points assume that ENET/QuadSPI/SAI etc. are active. If the same configuration is selected as per the S32K144, then the two devices will have very similar IDD.

### 4.7.1 Modes configuration

Attached *S32K1xx\_Power\_Modes\_Configuration.xlsx* details the modes used in gathering the power consumption data stated in the above table [Table 7](#). For full functionality refer to table: Module operation in available low power modes of the *Reference Manual*.

## 4.8 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
$V_{\text{HBM}}$	Electrostatic discharge voltage, human body model	– 4000	4000	V	<a href="#">1</a>
$V_{\text{CDM}}$	Electrostatic discharge voltage, charged-device model				<a href="#">2</a>
	All pins except the corner pins	– 500	500	V	
	Corner pins only	– 750	750	V	
$I_{\text{LAT}}$	Latch-up current at ambient temperature of 125 °C	– 100	100	mA	<a href="#">3</a>

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

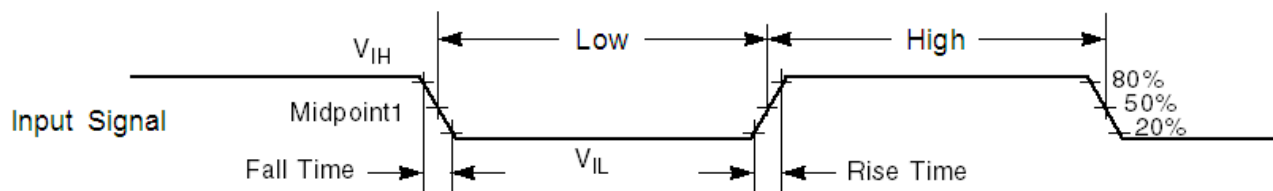
## 4.9 EMC radiated emissions operating behaviors

EMC measurements to IC-level IEC standards are available from NXP on request.

# 5 I/O parameters

## 5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is  $V_{IL} + (V_{IH} - V_{IL})/2$ .

**Figure 7. Input signal measurement reference**

## 5.2 General AC specifications

These general purpose specifications apply to all signals configured for GPIO, UART, and timers.

**Table 8. General switching specifications**

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1, 2
	GPIO pin interrupt pulse width (digital glitch filter disabled, passive filter disabled) — Asynchronous path	50	—	ns	3
WFRST	RESET input filtered pulse	—	100	ns	4
WFRST	RESET input not filtered pulse	100	—	ns	

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop and VLPS modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater of synchronous and asynchronous timing must be met.
3. These pins do not have a passive filter on the inputs. This is the shortest pulse width that is guaranteed to be recognized.
4. Minimum length of  $\overline{\text{RESET}}$  pulse, guaranteed not to be filtered by the internal filter.

## 5.3 DC electrical specifications at 3.3 V Range

**Table 9. DC electrical specifications at 3.3 V Range**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
$V_{DD}$	I/O Supply Voltage	2.7	3.3	4	V	1
$V_{ih}$	Input Buffer High Voltage	$0.7 \times V_{DD}$	—	$V_{DD} + 0.3$	V	2
$V_{il}$	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.3 \times V_{DD}$	V	3
$V_{hys}$	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
Ioh_Standard	I/O current source capability measured when pad = ( $V_{DDE} - 0.8$ V)	3.5	—	—	mA	

Table continues on the next page...



**Table 9. DC electrical specifications at 3.3 V Range (continued)**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
Iol_Standard	I/O current sink capability measured when pad = 0.8 V	3	—	—	mA	
Ioh_Strong	I/O current source capability measured when pad = ( $V_{DDE} - 0.8$ V)	14	—	—	mA	4
Iol_Strong	I/O current sink capability measured when pad = 0.8 V	12	—	—	mA	5
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 3.3$ V					6
	All pins other than high drive port pins		0.005	0.5	$\mu$ A	
	High drive port pins <sup>7</sup>		0.010	0.5	$\mu$ A	
R <sub>PU</sub>	Internal pullup resistors	20		60	k $\Omega$	8
R <sub>PD</sub>	Internal pulldown resistors	20		60	k $\Omega$	9

1. S32K148 will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged S32K148 is guaranteed to operate from 2.97 V. All other S32K family devices operate from 2.7 V in all modes.
2. For reset pads, same  $V_{ih}$  levels are applicable
3. For reset pads, same  $V_{il}$  levels are applicable
4. The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh\_Standard value given above.
5. The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol\_Standard value given above.
6. Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *S32K144\_IO\_Signal\_Description\_Input\_Multiplexing.xlsx* attached with the *Reference Manual*.
7. When using ENET and SAI on S32K148, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
8. Measured at input  $V = V_{SS}$
9. Measured at input  $V = V_{DD}$

## 5.4 DC electrical specifications at 5.0 V Range

**Table 10. DC electrical specifications at 5.0 V Range**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
$V_{DD}$	I/O Supply Voltage	4	—	5.5	V	
$V_{ih}$	Input Buffer High Voltage	$0.65 \times V_{DD}$	—	$V_{DD} + 0.3$	V	1
$V_{il}$	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.35 \times V_{DD}$	V	2
$V_{hys}$	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
Ioh_Standard	I/O current source capability measured when pad = ( $V_{DDE} - 0.8$ V)	5	—	—	mA	
Iol_Standard	I/O current sink capability measured when pad = 0.8 V	5	—	—	mA	

Table continues on the next page...

**Table 10. DC electrical specifications at 5.0 V Range (continued)**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
Ioh_Strong	I/O current source capability measured when pad = $V_{DDE} - 0.8\text{ V}$	20	—	—	mA	3, 4
Iol_Strong	I/O current sink capability measured when pad = 0.8 V	20	—	—	mA	4, 5
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5\text{ V}$					6
	All pins other than high drive port pins		0.005	0.5	$\mu\text{A}$	
	High drive port pins		0.010	0.5	$\mu\text{A}$	
R <sub>PU</sub>	Internal pullup resistors	20		50	k $\Omega$	7
R <sub>PD</sub>	Internal pulldown resistors	20		50	k $\Omega$	8

1. For reset pads, same  $V_{ih}$  levels are applicable
2. For reset pads, same  $V_{il}$  levels are applicable
3. The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh\_Standard value given above.
4. The strong pad I/O pin is capable of switching a 50 pF load at up to 40 MHz.
5. The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol\_Standard value given above.
6. Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *SK3K144\_IO\_Signal\_Description\_Input\_Multiplexing.xlsx* attached with the *Reference Manual*.
7. Measured at input  $V = V_{SS}$
8. Measured at input  $V = V_{DD}$

## 5.5 AC electrical specifications at 3.3 V range

**Table 11. AC electrical specifications at 3.3 V Range**

Symbol	DSE	Rise time (nS) <sup>1</sup>		Fall time (nS) <sup>1</sup>		Capacitance (pF) <sup>2</sup>
		Min.	Max.	Min.	Max.	
Standard	NA	4.6	14.5	3.9	15.7	25
		7.2	23.7	6.2	26.2	50
		24.0	75.4	20.8	88.4	200
Strong	0	4.6	14.5	3.9	15.7	25
		7.2	23.7	6.2	26.2	50
		24.0	75.4	20.8	88.4	200
	1	2.0	5.8	1.8	6.1	25
		2.8	8.0	2.6	8.3	50
		7.0	20.7	6.0	22.4	200

1. For reference only. Run simulations with the IBIS model and your custom board for accurate results.
2. Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

## 5.6 AC electrical specifications at 5 V range

Table 12. AC electrical specifications at 5 V Range

Symbol	DSE	Rise time (nS) <sup>1</sup>		Fall time (nS) <sup>1</sup>		Capacitance (pF) <sup>2</sup>
		Min.	Max .	Min.	Max.	
Standard	NA	3.2	9.4	3.6	10.7	25
		5.4	15.7	5.1	17.4	50
		18.5	52.6	17.6	59.7	200
Strong	0	4.0	9.4	3.6	10.7	25
		5.8	15.7	5.1	17.4	50
		18.1	52.6	17.6	59.7	200
	1	1.6	4.6	1.5	5.0	25
		2.2	5.7	2.2	5.8	50
		5.6	14.6	5.0	15.4	200

1. For reference only. Run simulations with the IBIS model and your custom board for accurate results.
2. Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

## 5.7 Standard input pin capacitance

Table 13. Standard input pin capacitance

Symbol	Description	Min.	Max.	Unit
C <sub>IN_D</sub>	Input capacitance: digital pins	—	7	pF

### NOTE

Please refer to [External System Oscillator electrical specifications](#) for EXTAL/XTAL pins.

## 5.8 Device clock specifications

Table 14. Device clock specifications **1**

Symbol	Description	Min.	Max.	Unit
High Speed run mode <sup>2</sup>				
f <sub>SYS</sub>	System and core clock	—	112	MHz
f <sub>BUS</sub>	Bus clock	—	56	MHz
f <sub>FLASH</sub>	Flash clock	—	28	MHz
Normal run mode (S32K11x series)				

Table continues on the next page...

**Table 14. Device clock specifications 1 (continued)**

Symbol	Description	Min.	Max.	Unit
f <sub>SYS</sub>	System and core clock	—	48	MHz
f <sub>BUS</sub>	Bus clock	—	24	MHz
f <sub>FLASH</sub>	Flash clock	—	24	MHz
Normal run mode (S32K14x series) <sup>3</sup>				
f <sub>SYS</sub>	System and core clock	—	80	MHz
f <sub>BUS</sub>	Bus clock	—	40	MHz
f <sub>FLASH</sub>	Flash clock	—	26.67	MHz
VLPR mode <sup>4</sup>				
f <sub>SYS</sub>	System and core clock	—	4	MHz
f <sub>BUS</sub>	Bus clock	—	4	MHz
f <sub>FLASH</sub>	Flash clock	—	1	MHz
f <sub>ERCLK</sub>	External reference clock	—	16	MHz

1. Refer to the section [Feature comparison](#) for the availability of modes and other specifications.
2. Only available on some devices. See section [Feature comparison](#).
3. With SPLP as system clock source.
4. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

## 6 Peripheral operating requirements and behaviors

### 6.1 System modules

There are no electrical specifications necessary for the device's system modules.

### 6.2 Clock interface modules

#### 6.2.1 External System Oscillator electrical specifications

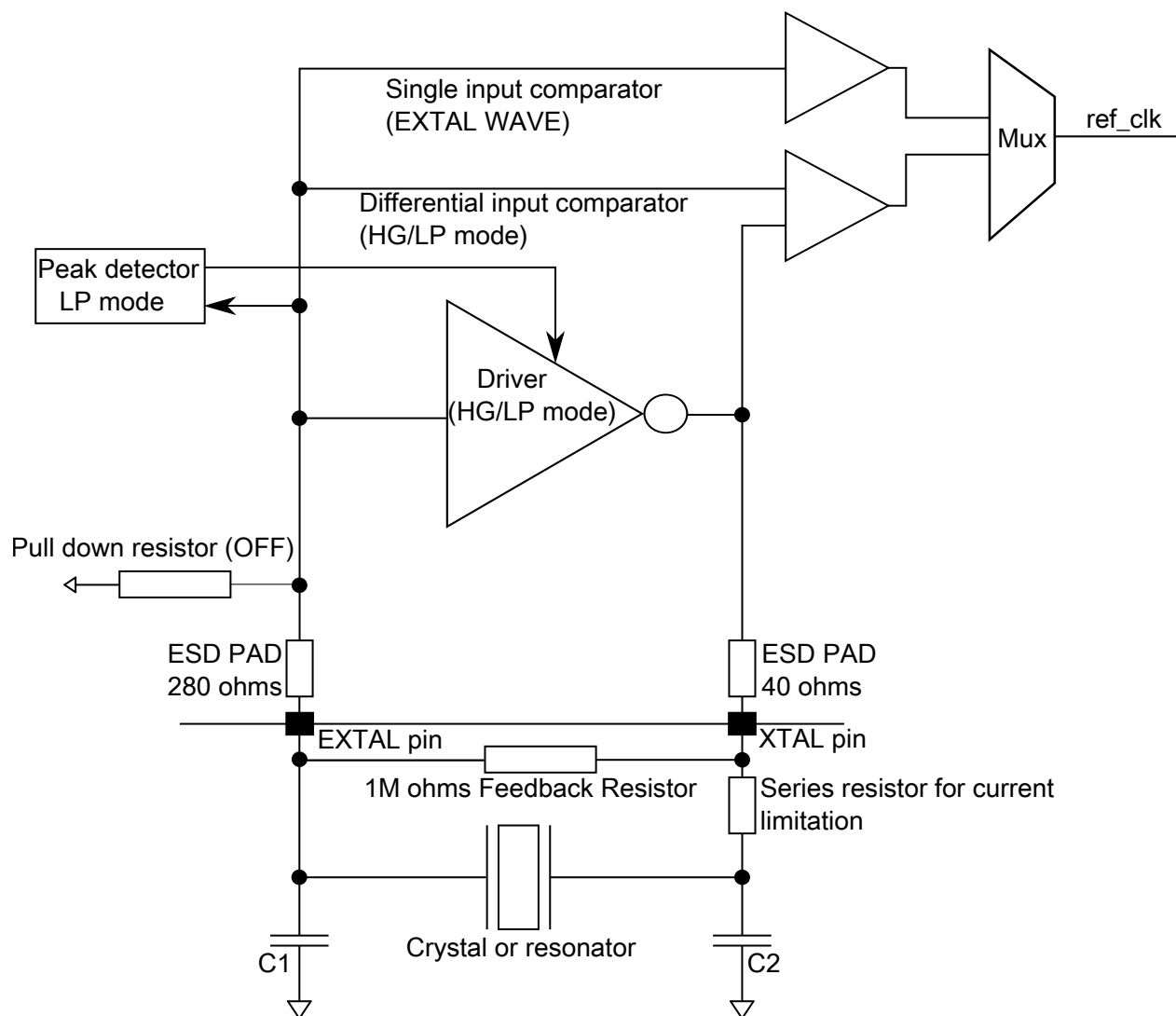


Figure 8. Oscillator connections scheme

Table 15. External System Oscillator electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$g_{mXOSC}$	Crystal oscillator transconductance					
	4-8 MHz	2.2	—	13.7	mA/V	
	8-40 MHz	16	—	47	mA/V	
$V_{IL}$	Input low voltage — EXTAL pin in external clock mode	$V_{SS}$	—	$0.35 * V_{DD}$	V	
$V_{IH}$	Input high voltage — EXTAL pin in external clock mode	$0.7 * V_{DD}$	—	$V_{DD}$	V	
$C_1$	EXTAL load capacitance	—	—	—		1
$C_2$	XTAL load capacitance	—	—	—		1
$R_F$	Feedback resistor					2
	Low-gain mode (HGO=0)	—	—	—	MΩ	

Table continues on the next page...

**Table 15. External System Oscillator electrical specifications  
(continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	High-gain mode (HGO=1)	—	1	—	MΩ	
R <sub>S</sub>	Series resistor					
	Low-gain mode (HGO=0)	—	0	—	kΩ	
	High-gain mode (HGO=1)	—	0	—	kΩ	
V <sub>pp</sub>	Peak-to-peak amplitude of oscillation (oscillator mode)					3
	Low-gain mode (HGO=0)	—	1.0	—	V	
	High-gain mode (HGO=1)	—	3.3	—	V	

1. Crystal oscillator circuit provides stable oscillations when  $g_{mXOSC} > 5 * g_{m\_crit}$ . The  $g_{m\_crit}$  is defined as:

$$g_{m\_crit} = 4 * ESR * (2\pi F)^2 * (C_0 + C_L)^2$$

where:

- $g_{mXOSC}$  is the transconductance of the internal oscillator circuit
- ESR is the equivalent series resistance of the external crystal
- F is the external crystal oscillation frequency
- $C_0$  is the shunt capacitance of the external crystal
- $C_L$  is the external crystal total load capacitance.  $C_L = C_s + [C_1 * C_2 / (C_1 + C_2)]$
- $C_s$  is stray or parasitic capacitance on the pin due to any PCB traces
- $C_1, C_2$  external load capacitances on EXTAL and XTAL pins

See manufacture datasheet for external crystal component values

- When low-gain is selected, internal R<sub>F</sub> will be selected and external R<sub>F</sub> should not be attached.
  - When high-gain is selected, external R<sub>F</sub> (1 M Ohm) needs to be connected for proper operation of the crystal. For external resistor, up to 5% tolerance is allowed.
- The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

## 6.2.2 External System Oscillator frequency specifications

**Table 16. External System Oscillator frequency specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f <sub>osc_hi</sub>	Oscillator crystal or resonator frequency	4	—	40	MHz	
f <sub>ec_extal</sub>	Input clock frequency (external clock mode)	—	—	50	MHz	
t <sub>dc_extal</sub>	Input clock duty cycle (external clock mode)	40	50	60	%	
t <sub>cst</sub>	Crystal Start-up Time					
	8 MHz low-gain mode (HGO=0)	—	1.5	—	ms	1
	8 MHz high-gain mode (HGO=1)	—	2.5	—		
	40 MHz low-gain mode (HGO=0)	—	2	—		
	40 MHz high-gain mode (HGO=1)	—	2	—		

- Proper PC board layout procedures must be followed to achieve specifications.